
5XCC0 Biopotential and Neural Interface Circuits

Amplifiers and Filters

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Outline

- Amplifier types
 - Transimpedance Amplifiers
 - Transconductance Amplifiers
 - Voltage Amplifiers
- Advanced Amplifier Techniques
- G_m -C Filters

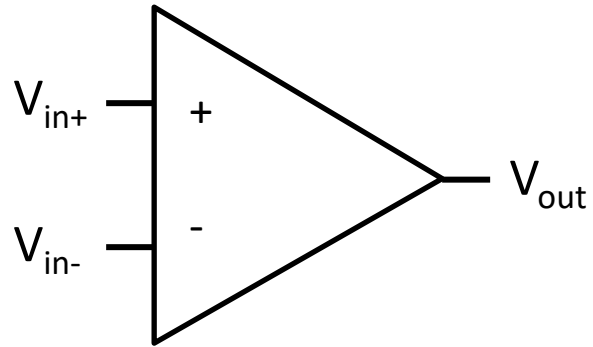
Basics

- You should be familiar with:
 - Differential pair
 - Current mirror
 - Common-mode, differential-mode
 - Common-mode feedback
 - Open-loop, closed-loop, stability, phase margin
- Recommended literature:
 - Razavi – “Design of Analog CMOS Integrated Circuits”
 - Sansen – “Analog Design Essentials”
 - Sarapeshkar – “Ultra Low Power Bioelectronics”

Amplifier types

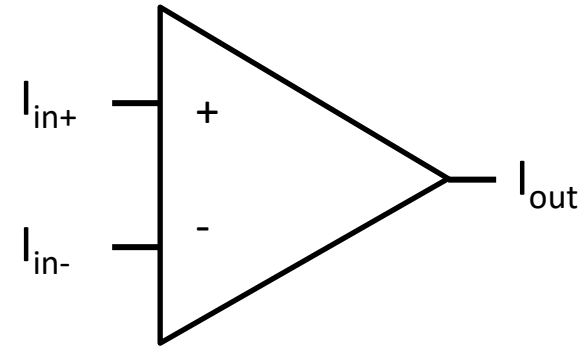
Voltage amplifier

$$V_{\text{out}} = A \cdot V_{\text{in}}$$



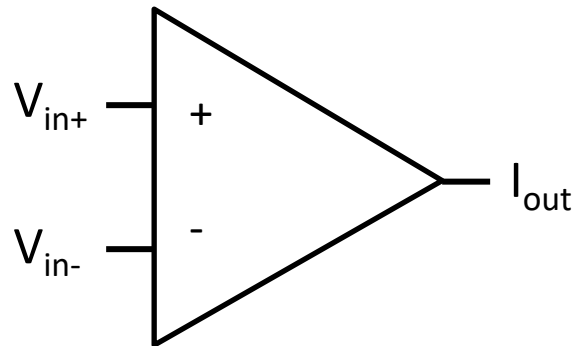
Current amplifier

$$I_{\text{out}} = A \cdot I_{\text{in}}$$



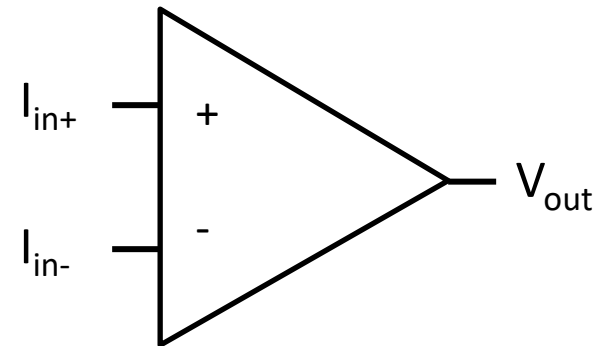
Transconductance amplifier

$$I_{\text{out}} = G_m \cdot V_{\text{in}}$$

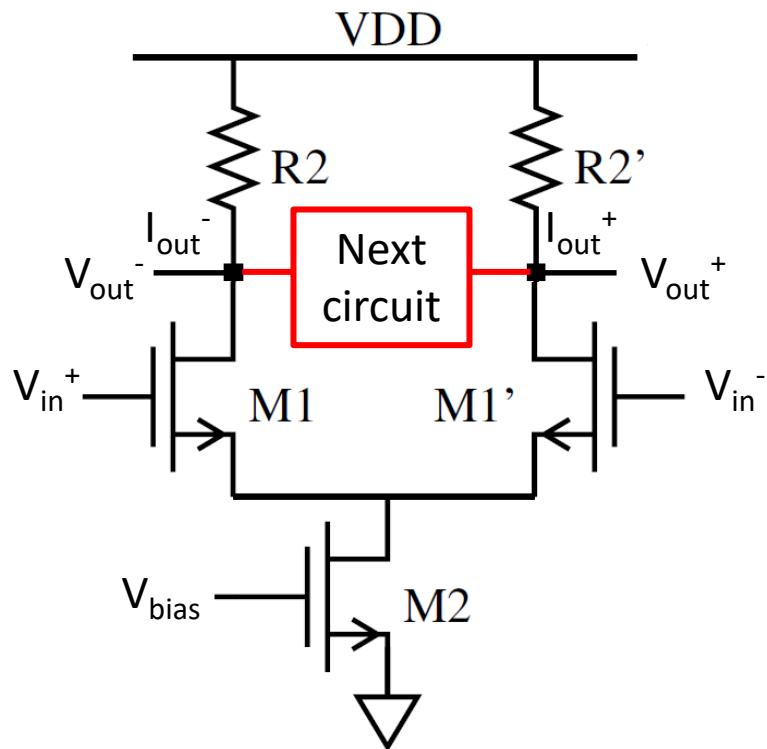


Transimpedance amplifier

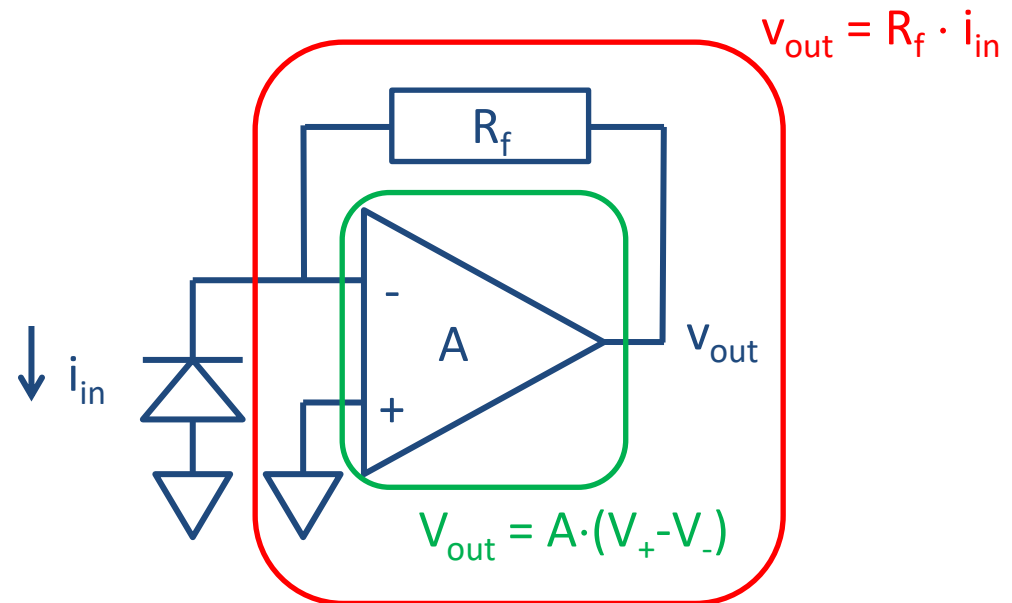
$$V_{\text{out}} = Z \cdot I_{\text{in}}$$



Amplifier types

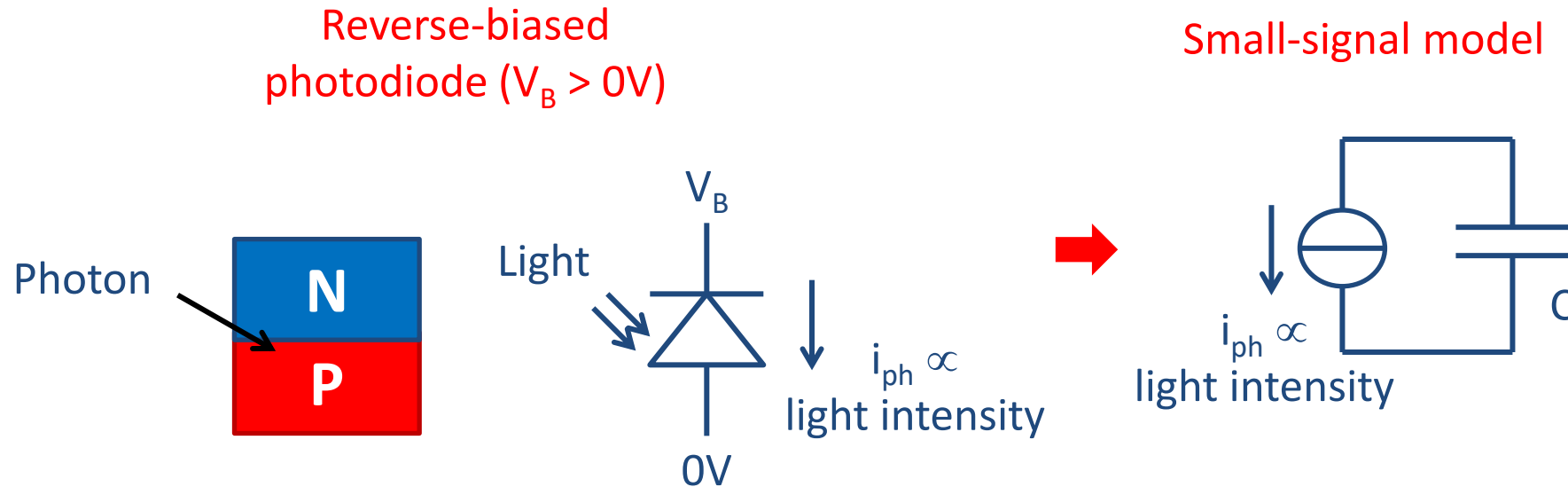


Amplifier type	Input	Output
Voltage	V	V
Transconductance	V	I
Transimpedance	I	V
Current	I	I



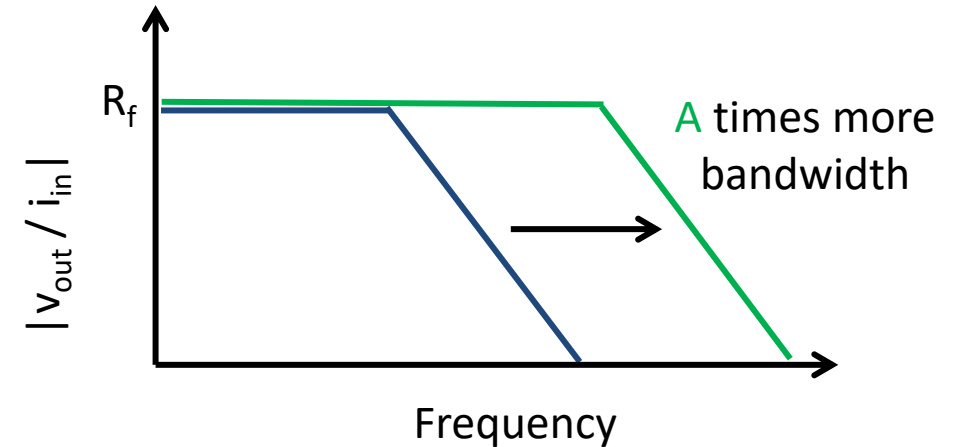
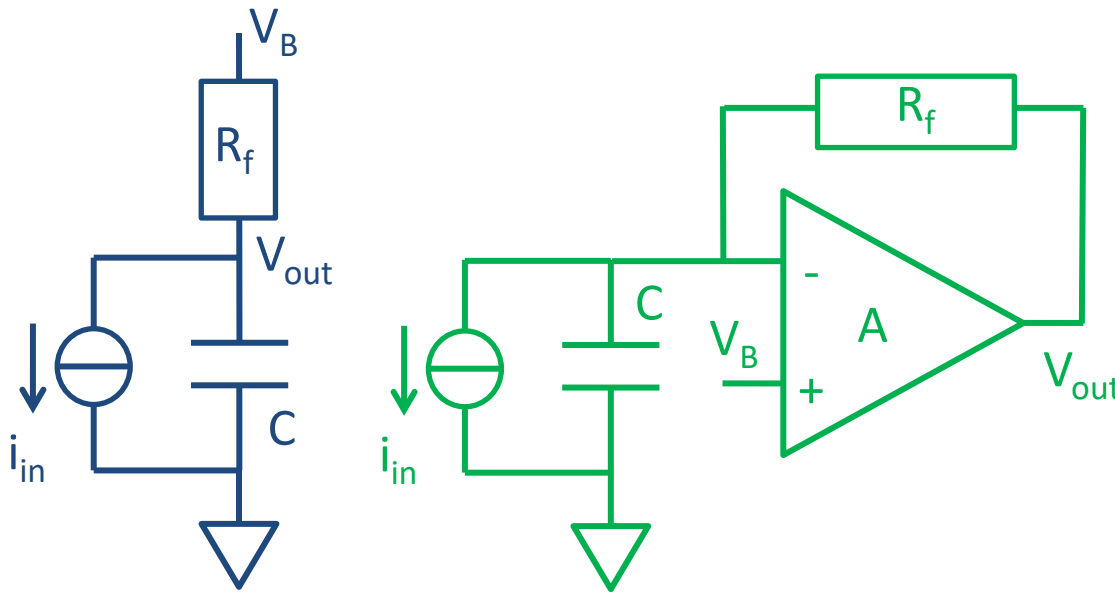
Photodiodes

- Photon generates electron/hole pair in PN junction →
Current created with the help of bias voltage V_B



Transimpedance Amplifier (TIA)

- Input I \rightarrow Output V
- Many sensors have a current output
 - Photodiode (image sensors)
 - Microphone (cochlear implant)
 - (Some) ultrasound transducers



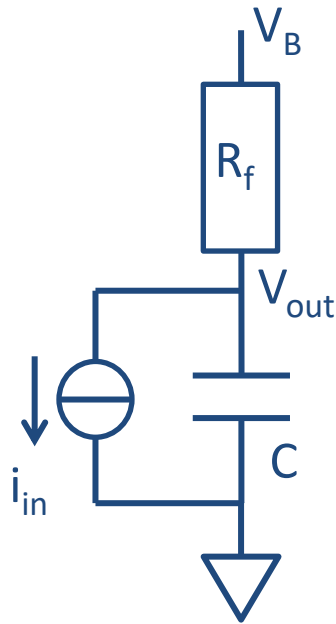
$$v_{out}/i_{in} \approx -R_f / (1 + s C R_f)$$

$$v_{out}/i_{in} \approx R_f / (1 + s C R_f / A)$$

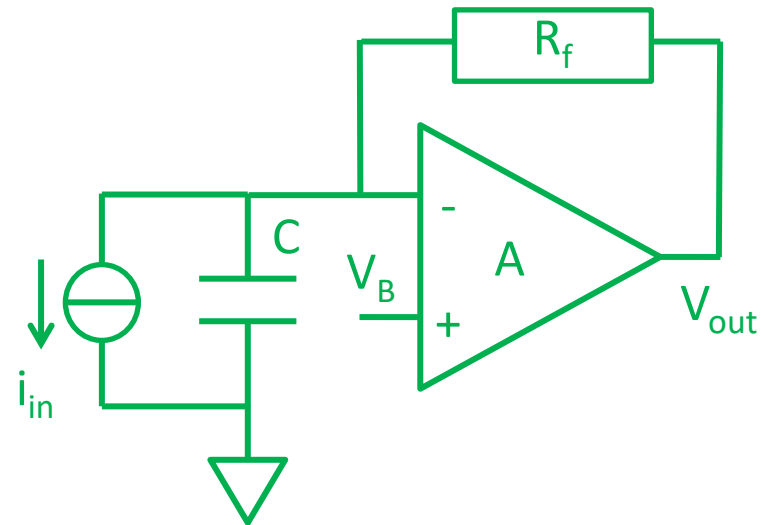
TIA increases BW by a factor A,
and sets sensor bias voltage precisely

Exercise 1: TIA

- a) Show that the two transfer functions as given on the previous slide (repeated here for convenience) are correct for the given circuits.



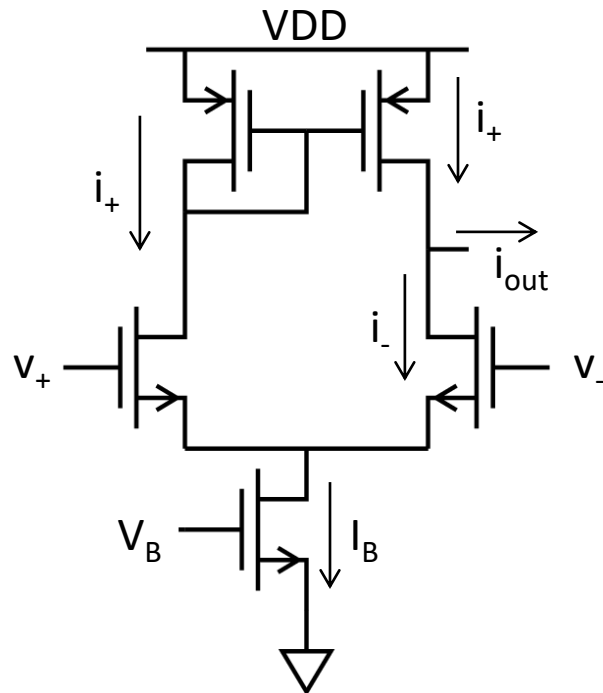
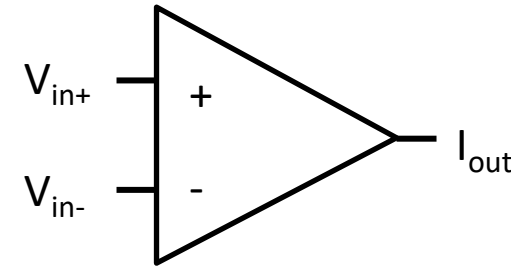
$$V_{out}/i_{in} \approx -R_f / (1 + s C R_f)$$



$$V_{out}/i_{in} \approx R_f / (1 + s C R_f / A)$$

Transconductance Amplifier

- OTA: Operational Transconductance Amplifier
- Input $V \rightarrow$ Output I
- $G_m: i_{out} = G_m v_{in}$



$$i_{out} = i_+ - i_-; v_{in} = v_+ - v_-$$

$$i_+ = g_m \cdot v_+; i_- = g_m \cdot v_-$$

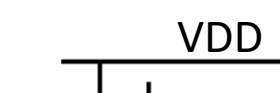
$$i_{out} = g_m \cdot v_+ - g_m \cdot v_- = g_m \cdot v_{in}$$

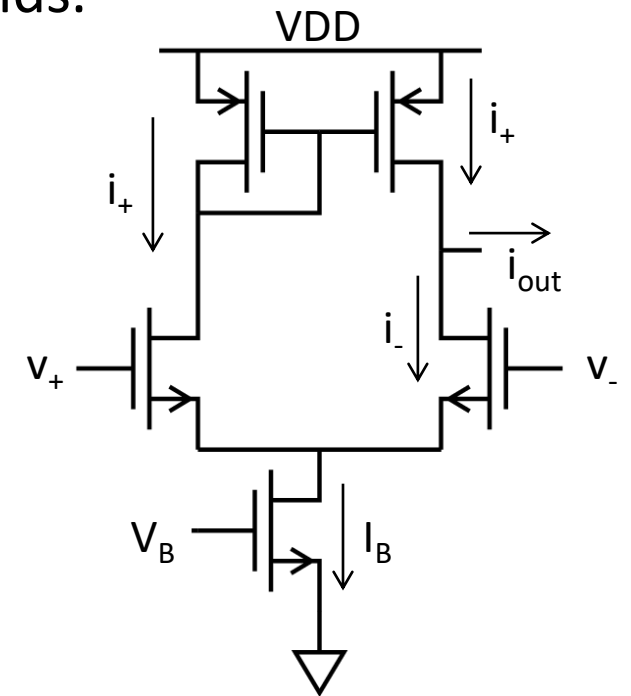
$$g_m = K_s / \Phi_t \cdot \frac{1}{2} I_B$$

$$i_{out} / v_{in} = G_m = K_s / \Phi_t \cdot \frac{1}{2} I_B$$

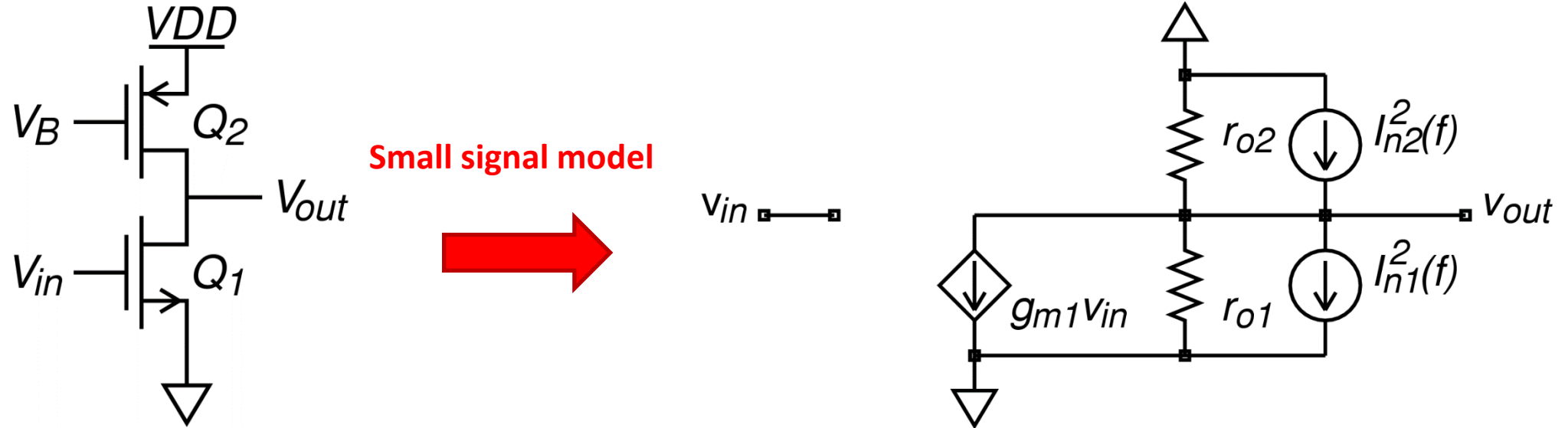
Exercise 2: OTA Noise

Consider the OTA also discussed on the previous slide.

- a) Express the input-referred noise power spectral density as function of the bias current I_B (and other parameters). You may assume that only the two input transistors are critical for the overall noise, that those transistors are biased in sub-threshold, and that for each transistor $V_{gn}^2(f) = kT / 9I_{DS}$ holds.
- b) Assume that we need an OTA which has a total input-referred noise power of $2\mu V_{rms}$ in a bandwidth of 10kHz. How should we set I_B ?
- 



Common-Source (CS) Voltage Amplifier (VA)



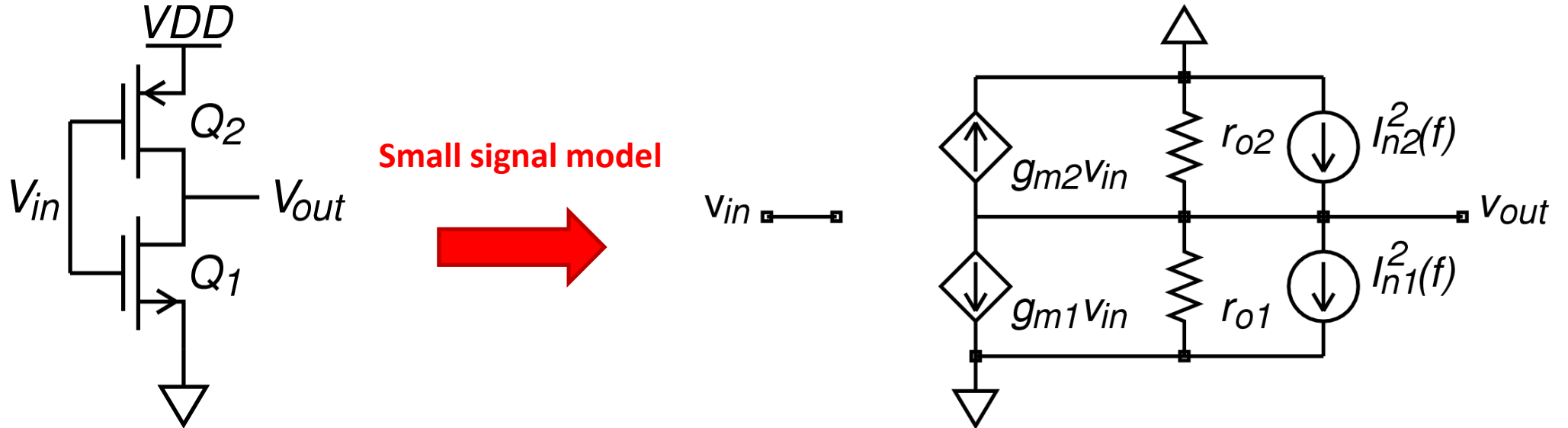
- Gain:

$$A = -g_{m1} \cdot (r_{o1} // r_{o2})$$

- Input-referred noise:

$$V_n^2(f) = \{I_{n1}^2(f) + I_{n2}^2(f)\} / g_{m1}^2$$

Inverter-Based Voltage Amplifier



- Gain:

$$A = -(g_{m1} + g_{m2}) \cdot (r_{o1} // r_{o2})$$

- Input-referred noise:

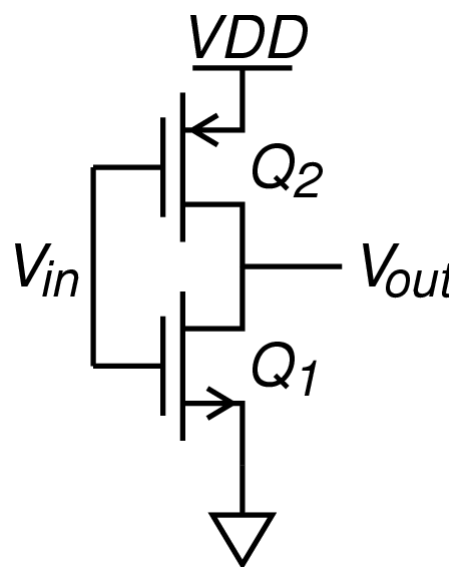
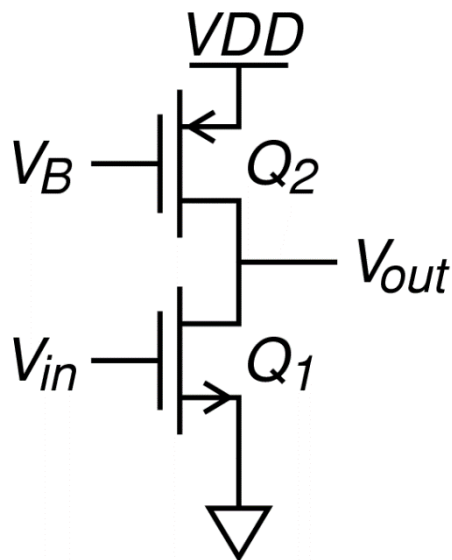
$$V_n^2(f) = \{I_{n1}^2(f) + I_{n2}^2(f)\} / (g_{m1} + g_{m2})^2$$

More gain (about 2x) and lower input-referred noise power spectral density (about 4x) compared to CS VA

Exercise 3: CS VA versus INV VA

Assume that the bias current for the circuits below is set to $1\mu\text{A}$ and assume that all transistors are biased in sub-threshold.

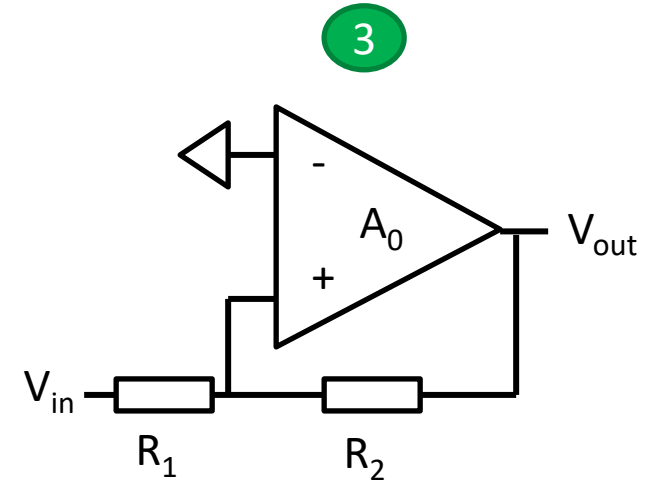
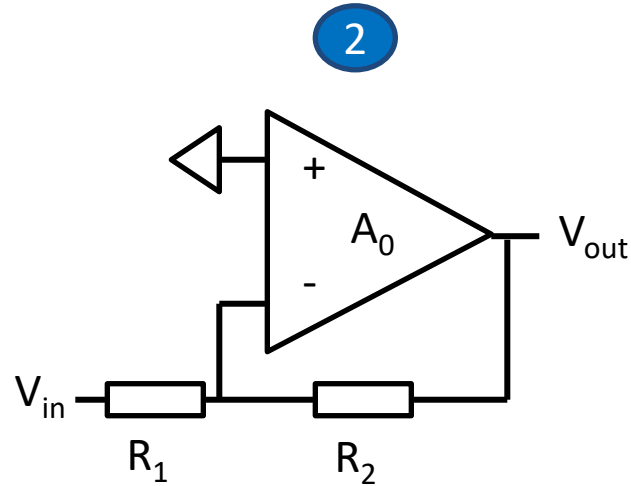
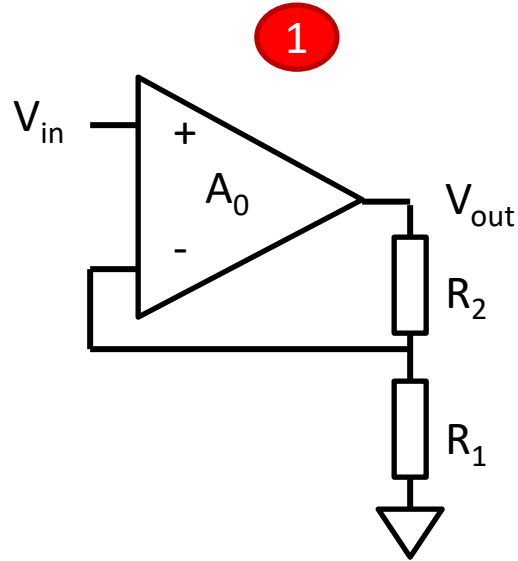
- a) For the CS VA, what will be the input-referred noise power spectral density?
- b) For the INV VA, what will be the input-referred noise power spectral density?



Low-Voltage Analog Design

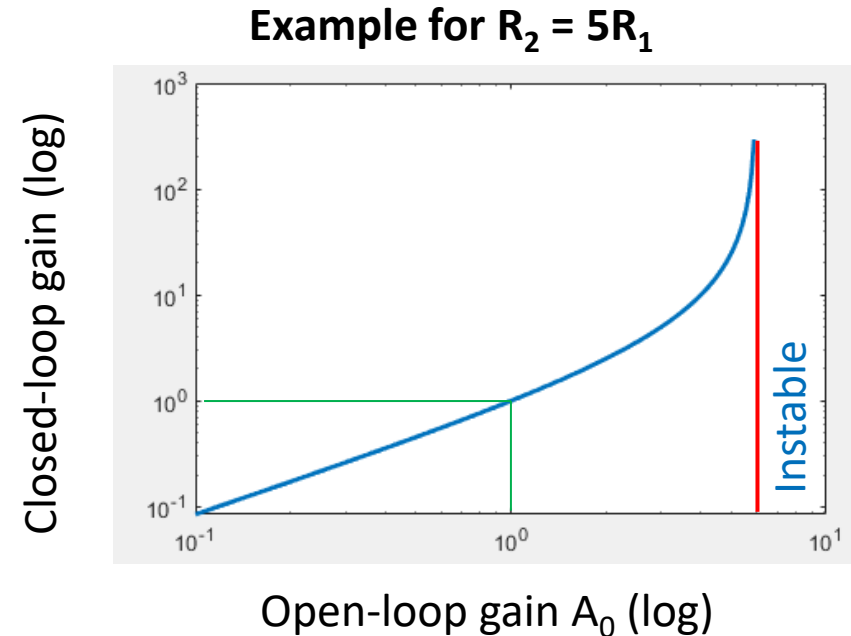
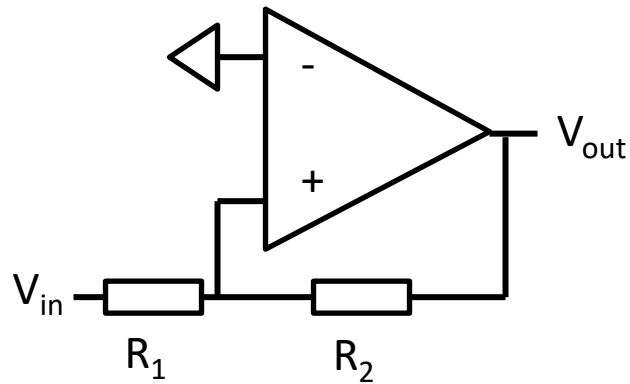
- Each transistor needs a certain V_{DSAT} →
 - Minimize number of stacked transistors
 - Use sub-threshold biasing (lower V_{DSAT})
- Use cascaded stages rather than cascoded transistors to increase gain
- Increase DC gain by positive feedback

Positive Feedback Loops



- $V_{out} = A_0 \cdot (V_+ - V_-)$; what is the closed-loop gain $A_{cl} = V_{out}/V_{in}$?
 - (1): negative feedback, non-inverting amplifier, $|A_{cl}| < A_0$
 - (2): negative feedback, inverting amplifier, $|A_{cl}| < A_0$
 - (3): positive feedback, non-inverting amplifier, $|A_{cl}| > A_0$

Positive Feedback to Enhance Gain

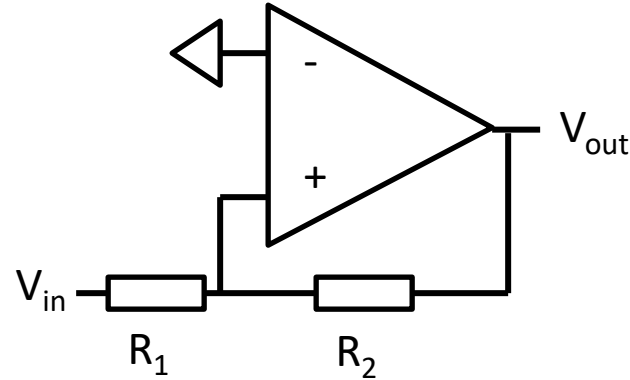


- $A_{cl} = V_{out}/V_{in} = A_0 R_2 / [R_1 + R_2 - A_0 R_1]$
- Only stable when $R_1 + R_2 - A_0 R_1 > 0$
- Gain can be $> A_0$!

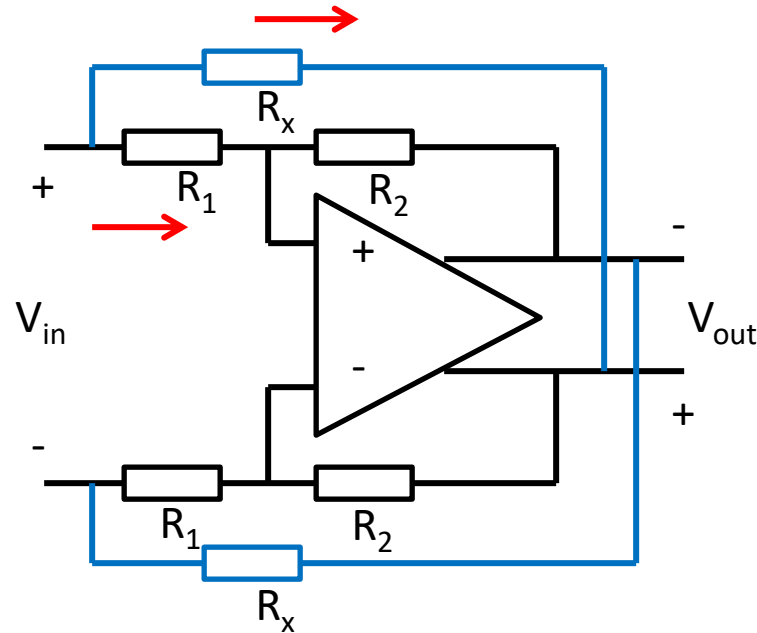
A_0	A_{cl}
$A_0 < 1$	$A_{cl} < 1$
$A_0 = 1$	$A_{cl} = 1$
$A_0 > 1$	$A_{cl} > A_0$

Exercise 4: Positive Feedback to Enhance Gain

- a) For the circuit below, assume that the amplifier's open-loop gain is $20x$ and that $R_2 = 1\text{M}\Omega$. What should the value of R_1 be to reach a closed-loop gain of $100x$?



Positive Feedback to Enhance Z_{in}



$$I_{in} = I_{R1} + I_{Rx}$$

$$I_{R1} = 0.5V_{in} / R_1$$

$$I_{Rx} = (0.5V_{in} - 0.5V_{out}) / R_x$$

For $Z_{in} = \infty$, $I_{in} = 0$:

$$0.5V_{in} / R_1 + (0.5V_{in} - 0.5V_{out}) / R_x = 0$$

Since $V_{out} = R_2 / R_1 V_{in}$, this leads to:

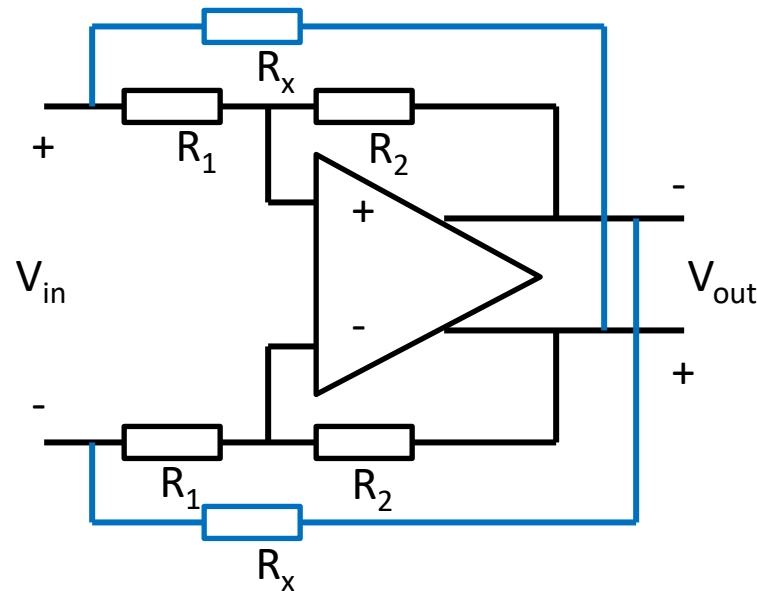
$$R_x = R_2 - R_1$$

- $V_{out} = R_2 / R_1 \cdot V_{in}$
- What is the input impedance?
- $Z_{in} \approx 2R_1$ (differential)
- With positive feedback, Z_{in} can be increased to infinity (theory)

Exercise 5: Positive Feedback to Enhance Z_{in}

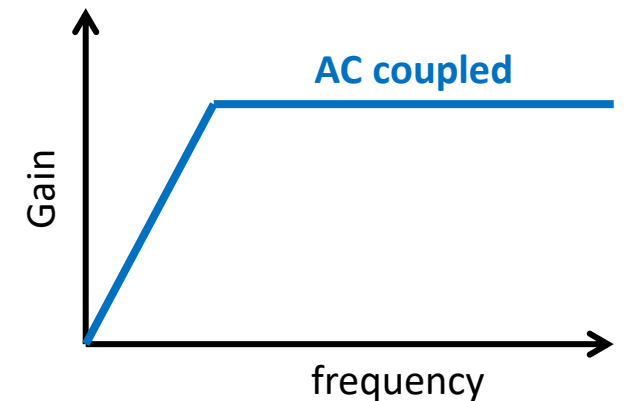
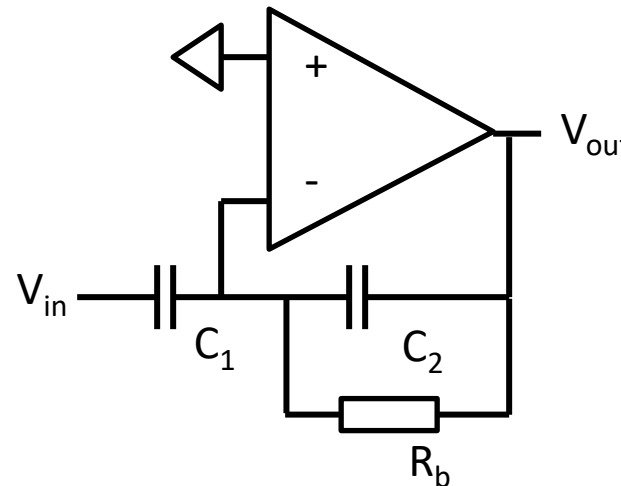
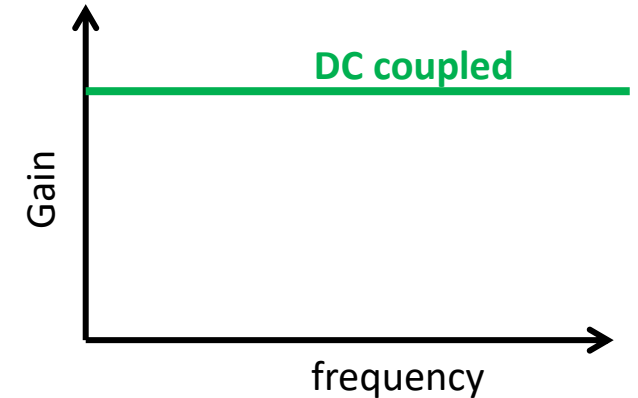
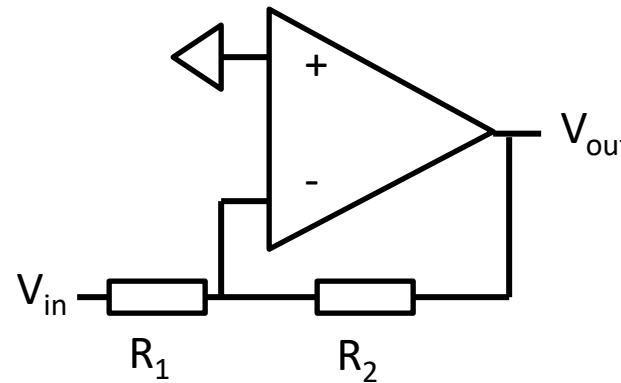
For the circuit below, assume that the amplifier's open-loop gain is infinite and that $R_1 = 1\text{M}\Omega$. For questions a) and b), you may assume R_x is not yet present.

- a) What should the value of R_2 be, to get a closed-loop gain of 100x?
- b) What is the differential input impedance of the circuit?
- c) If we add R_x , and if R_x is chosen equal to R_2 , what will the differential input impedance then be?



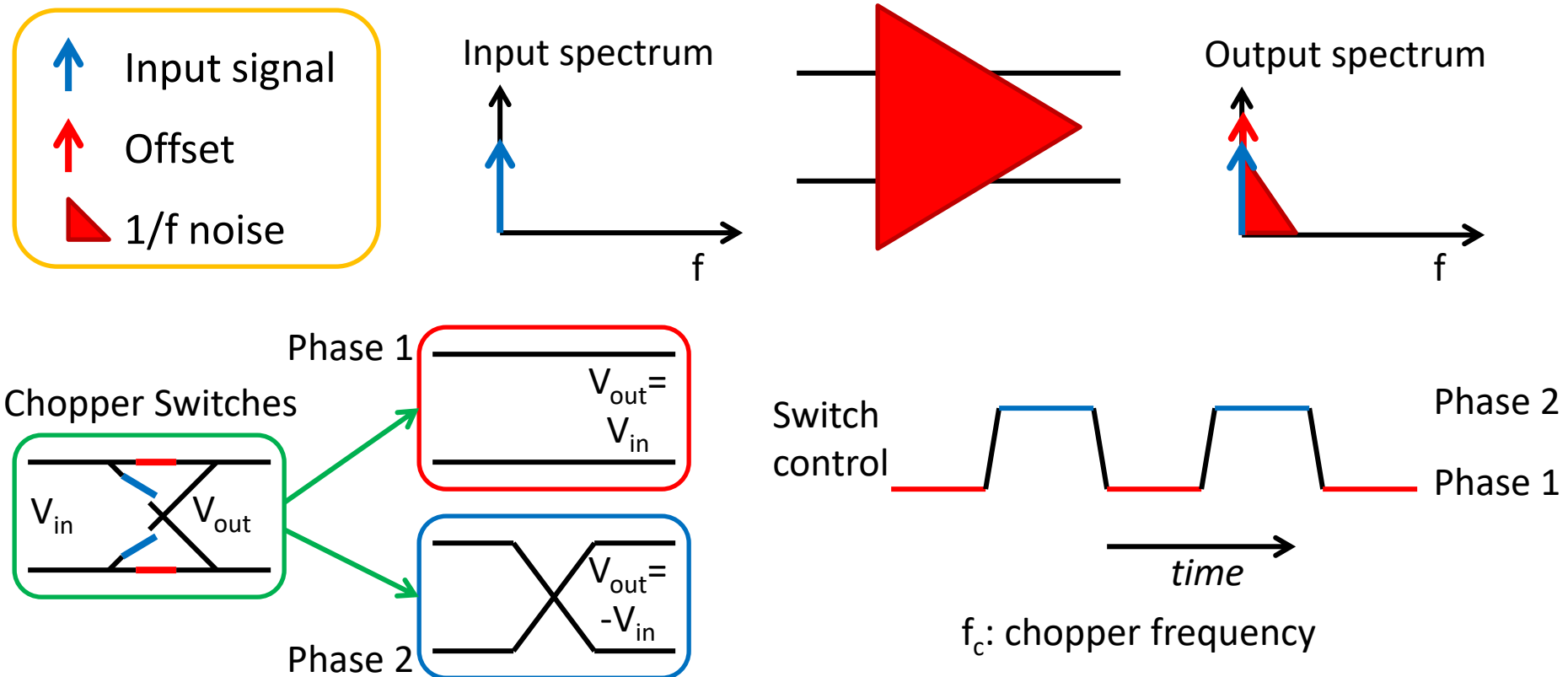
Capacitively-Coupled Amplifiers

- Gain: R_2 / R_1
 - R_2 and R_1 contribute in-band noise ($4kTR$)
- Gain: C_1 / C_2
 - Does not work for DC signals
 - Bias resistor (R_b) needed
 - Most of the noise of R_b is out of band

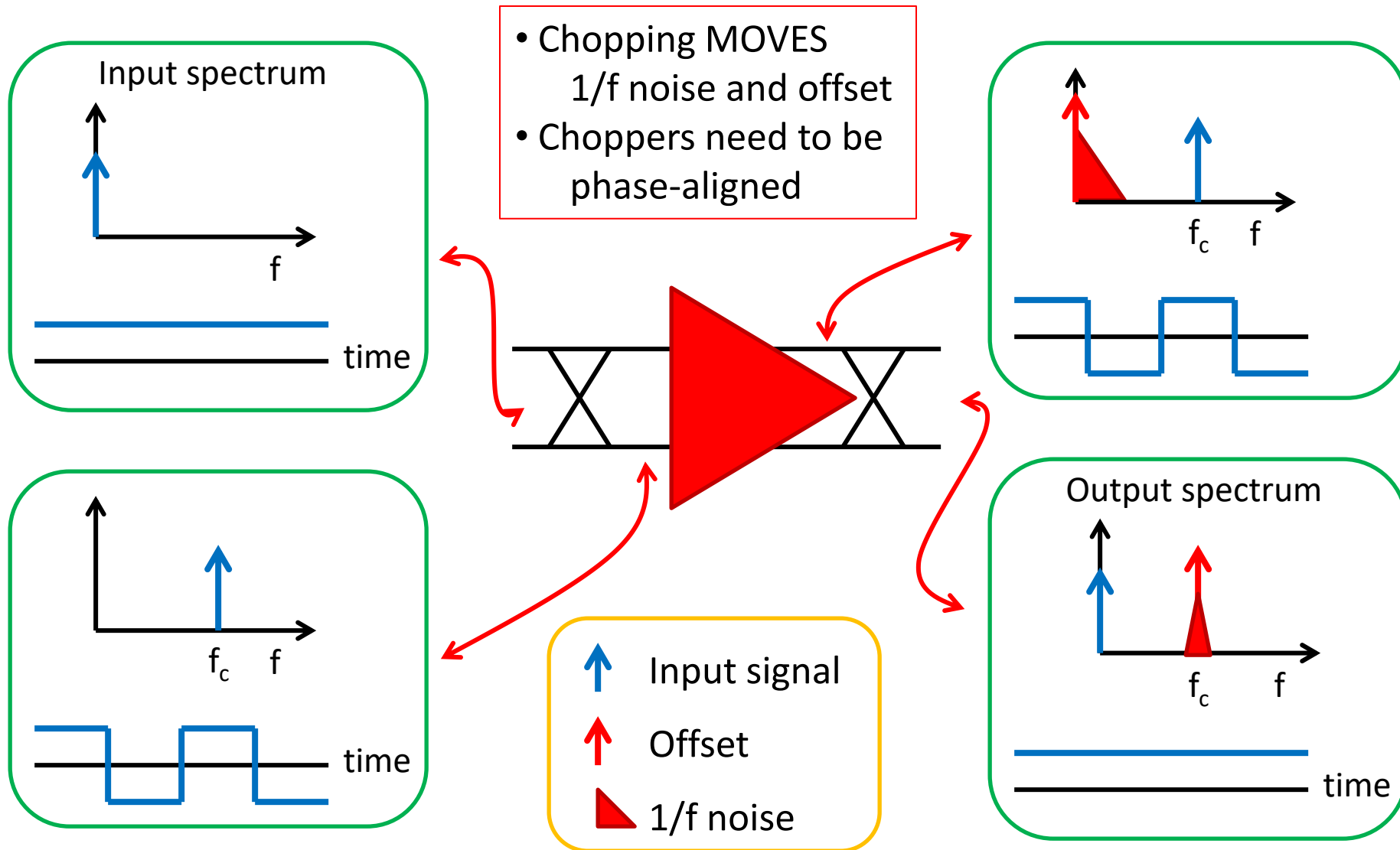


Chopping Amplifier (1)

- Input is a DC (or low-frequency) signal
- Amplifier with $1/f$ noise and offset



Chopping Amplifier (2)



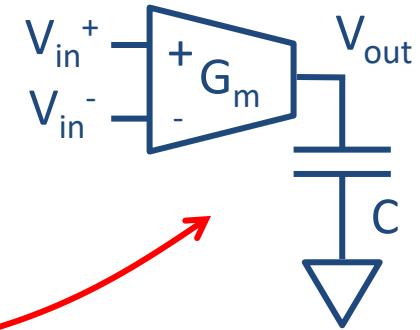
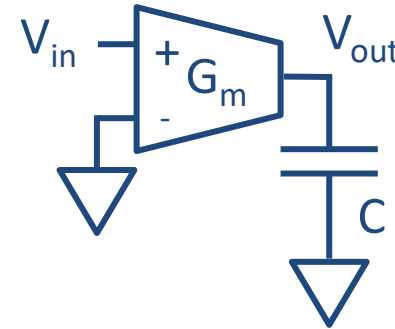
Filters

- Passive RLC filters
 - Large L and C values for low frequencies → Cannot be integrated in an IC
- Opamp-RC
 - Overdesigned GBW needed → Power hungry
- Switched capacitor
 - Opamps and f_{switch} far beyond bandwidth → Power hungry
- Mosfet-RC
 - Transistors are non-linear → Filter will have poor linearity
- G_m -C filters
 - Open-loop G_m stages → Power-efficient, modest linearity

G_m -C Filters

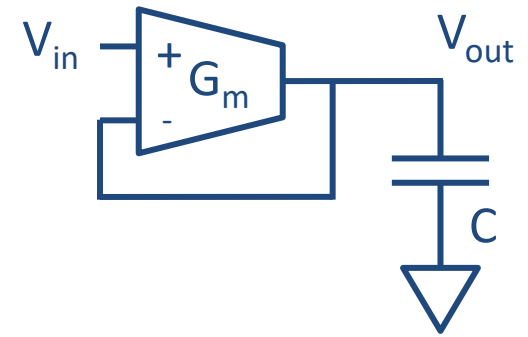
- Basic stage: $G_m + C$, acts as integrator:

- $H(s) = 1/s\tau$, with $\tau = C / G_m$
- $V_{out}(s) = 1 / s\tau \cdot V_{in}(s)$
- $V_{out}(s) = 1 / s\tau \cdot (V_{in}^+(s) - V_{in}^-(s))$



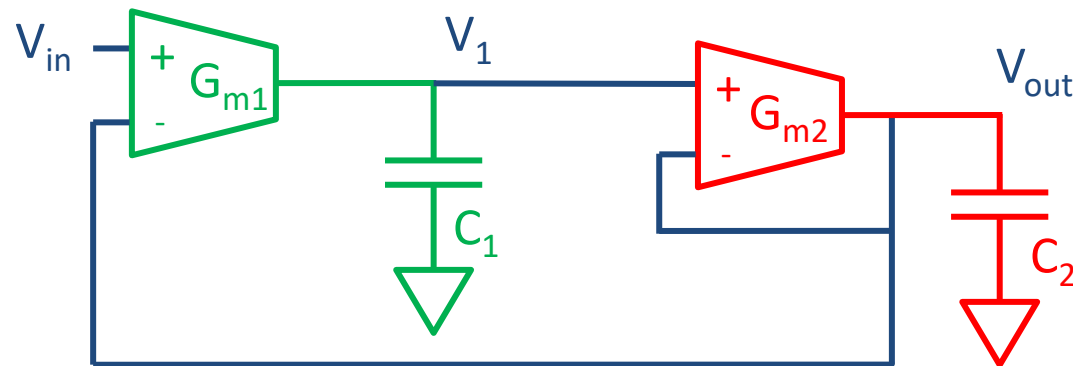
- How to synthesize: 1st order filter example

- $V_{out}(s) / V_{in}(s) = 1 / (s\tau + 1)$
- $V_{out}(s) (s\tau + 1) = V_{in}(s)$
- $V_{out}(s) s\tau = V_{in}(s) - V_{out}(s)$
- $V_{out}(s) = 1 / s\tau \cdot (V_{in}(s) - V_{out}(s))$



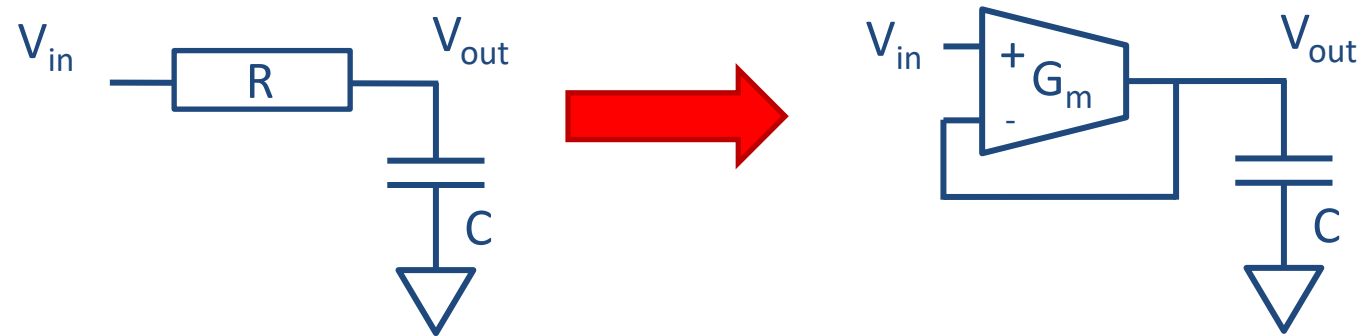
2nd Order G_m -C Filter

- $V_{out}(s) / V_{in}(s) = 1 / (\tau_1 \tau_2 s^2 + \tau_1 s + 1)$
- $V_{out}(s) \cdot (\tau_1 \tau_2 s^2 + \tau_1 s + 1) = V_{in}(s)$
- $V_{out}(s) \cdot \tau_1 s (\tau_2 s + 1) = V_{in}(s) - V_{out}(s)$
- $V_{out}(s) \cdot (\tau_2 s + 1) = 1 / s \tau_1 (V_{in}(s) - V_{out}(s))$
- $V_{out}(s) \cdot \tau_2 s = 1 / s \tau_1 (V_{in}(s) - V_{out}(s)) - V_{out}(s)$
- $V_{out}(s) = 1 / s \tau_2 \{ 1 / s \tau_1 (V_{in}(s) - V_{out}(s)) - V_{out}(s) \}$



Higher-Order G_m -C Filters

- Either use:
 - Concatenation of 1st and 2nd order stages
 - Apply element replacement synthesis method:
 $\{R, L, C\}$ is replaced by its equivalent in G_m -C
e.g.: $V_{out}(s) / V_{in}(s) = 1 / (s\tau + 1)$



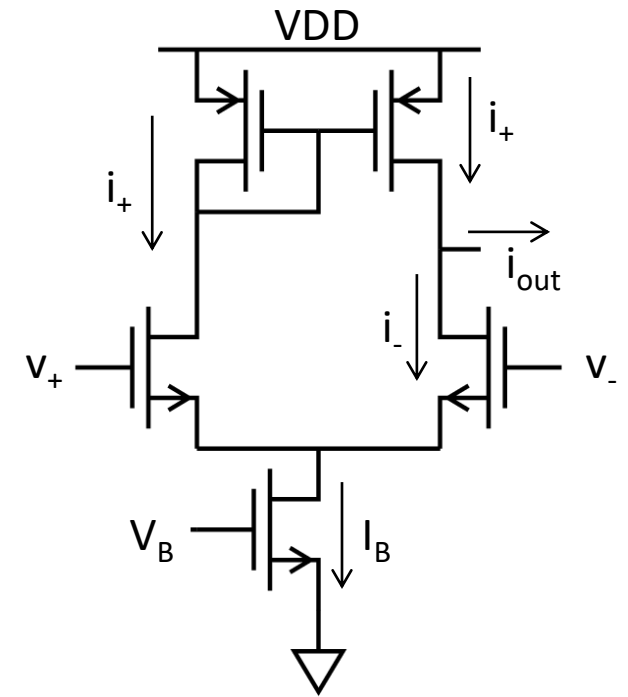
Noise in G_m -C Filters

- Before:
 - RC filter, S&H: $P_{\text{noise}} = kT / C$
- G_m/C filter: $P_{\text{noise}} \propto kT / C$
- Approach:
 - Size the capacitors based on the noise requirement
 - Determine G_m 's to reach the proper $\tau = C / G_m$
 - Calculate I_{BIAS} currents for each G_m stage

Exercise 6: First-Order G_m -C filter

We would like to design a first-order G_m -C low-pass filter with a cut-off frequency of 2kHz. It is already given that $C = 100\text{fF}$.

- a) What is the circuit topology that we need for this filter?
- b) What is the required value of G_m ?
- c) Assuming we use the OTA given below, and assuming it is biased in sub-threshold, what is thus the required bias current I_B ?



Summary

- Amplifiers
- Positive feedback to increase gain or input impedance
- Chopping amplifiers
- G_m -C filters

Solution 1: TIA

a)

- First circuit:
 - KCL: $i_{in} + V_{out} sC + (V_{out} - V_B) / R_f = 0$
 - When determining the transfer function from source i_{in} to output V_{out} , you may set the other sources to 0, so $V_B = 0V$.
 - $i_{in} + v_{out} sC + v_{out} / R_f = 0$
 - $v_{out} / i_{in} = -R_f / (1 + s C R_f)$
- Second circuit:
 - Amplifier equation: $V_{out} = A (V_+ - V_-) = A (V_B - V_-)$
 - KCL: $i_{in} + V_- sC + (V_- - V_{out}) / R_f = 0$
 - Combining the above equations and setting V_B to 0V as before:
 - $v_- = -v_{out} / A$
 - $i_{in} - v_{out} sC / A - v_{out} (1 / A + 1) / R_f = 0$
 - $v_{out} / i_{in} \approx R_f / (1 + s C R_f / A)$

Solution 2: OTA Noise

- a) Each of the two input transistors has a gate noise of $V_{gn}^2(f) = kT / 9I_{DS}$.
Together, that gives a total IRN of $V_{in,n}^2(f) = 2kT / 9I_{DS}$.
 $I_{DS} = \frac{1}{2} I_B$, so the overall IRN as function of I_B is $V_{in,n}^2(f) = 4kT / 9I_B$.
- b) $2\mu V_{rms}$ means a total noise power of $4pV^2$ in the 10kHz BW.
This is equivalent to a PSD of $V_{in,n}^2(f) = 4pV^2 / 10kHz = 0.4fV^2/Hz$.
So: $0.4fV^2/Hz = 4kT / 9I_B$, which results in an I_B of $4.6\mu A$.

Solution 3: CS VA versus INV VA

Assume that the bias current for the circuits below is set to $1\mu\text{A}$ and assume that all transistors are biased in sub-threshold.

a) $V_n^2(f) = \{I_{n1}^2(f) + I_{n2}^2(f)\} / g_{m1}^2$.

$I_{n1}^2(f) = I_{n2}^2(f) = 2qI_D$, with $I_D = 1\mu\text{A}$.

We can estimate g_{m1} by e.g.: $g_{m1} \approx 25I_D = 25\mu\text{A/V}$.

Solving this gives: $V_n^2(f) \approx 1\text{fV}^2/\text{Hz}$.

b) $V_n^2(f) = \{I_{n1}^2(f) + I_{n2}^2(f)\} / (g_{m1} + g_{m2})^2$

The values are the same as before and $g_{m2} = g_{m1}$.

Solving this gives: $V_n^2(f) \approx 0.26\text{fV}^2/\text{Hz}$.

Solution 4: Positive Feedback to Enhance Gain

- a) Amplifier equation: $V_{\text{out}} = AV_+$, where $A = 20$.
KCL: $(V_+ - V_{\text{in}}) / R_1 + (V_+ - V_{\text{out}}) / R_2 = 0$, where $R_2 = 1\text{M}\Omega$.
Final goal: $V_{\text{out}} = 100V_{\text{in}}$.

Combining the equations gives:

$$V_+ = 0.05V_{\text{out}}$$

$$V_{\text{in}} = 0.01V_{\text{out}}$$

$$(0.05V_{\text{out}} - 0.01V_{\text{out}}) / R_1 + (0.05V_{\text{out}} - V_{\text{out}}) / 1\text{M}\Omega = 0$$

$$0.04 / R_1 = 0.95 / 1\text{M}\Omega \rightarrow R_1 = 42\text{k}\Omega.$$

Solution 5: Positive Feedback to Enhance Z_{in}

a) $R_2 = 100\text{M}\Omega$, because the closed-loop gain is R_2/R_1 .

b) $2R_1 = 2\text{M}\Omega$.

c) Analyzing single-ended:

$$i_{in} = i_{R1} + i_{Rx} = 0.5v_{in} / R_1 + (0.5v_{in} - 0.5v_{out}) / R_x.$$

$$v_{out} = 100 v_{in}.$$

$$R_x = R_2 = 100R_1.$$

$$Z_{in,diff} = 2Z_{in,single-ended} = v_{in} / i_{in}.$$

Combining the equations gives:

$$i_{in} = 0.5v_{in} / R_1 - 49.5v_{in} / R_x = v_{in} (0.5 / R_1 - 0.495 / R_1) = 0.005 v_{in} / R_1$$

$$Z_{in,diff} = v_{in} / i_{in} = 1 / (0.005 / R_1) = 200R_1 = 200\text{M}\Omega.$$

Solution 6: First-Order G_m -C filter

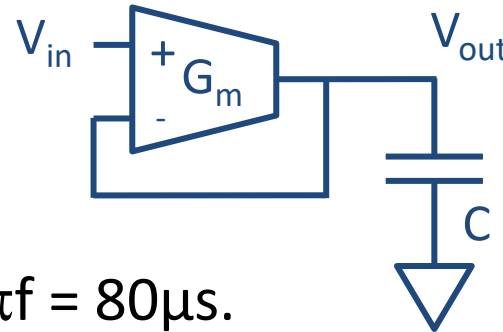
We would like to design a first-order G_m -C low-pass filter with a cut-off frequency of 2kHz. It is already given that $C = 100\text{fF}$.

- a) Topology as shown in figure

The equation for it is

$$V_{\text{out}}(s) / V_{\text{in}}(s) = 1 / (s\tau + 1)$$

where $\tau = C / G_m$



- b) 2kHz cut-off frequency, so $\tau = 1 / 2\pi f = 80\mu\text{s}$.

Since $C = 100\text{fF}$, that implies G_m must be $100\text{fF} / 80\mu\text{s} = 1.26\text{nA/V}$.

- c) For this OTA, the G_m is approximately $12.5I_B$. So $I_B = 0.1\text{nA}$.